Review Article
Nanodiamond Films for Applications in Electrochemical Systems

A. F. Azevedo, M. R. Baldan, and N. G. Ferreira
LAS, Instituto Nacional de Pesquisas Espaciais (INPE), CP 515, 12227-010 São José dos Campos, SP, Brazil
Correspondence should be addressed to A. F. Azevedo, adriana@las.inpe.br
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1. Introduction
Diamond nanocrystal is a topic of considerable interest in the scientific community, as properties of these systems are expected to retain a large extent of singular characteristics concerning polycrystalline diamond films [1]. The first reference related to these materials as “nanocrystalline” was presented in the Workshop on Diamond Thin Films in 1990 [2]. In 1994, Gruen and coworkers have reported that the growth of “fine-grained” or nanocrystalline diamond (NCD) films was obtained by Chemical Vapor Deposition (CVD) under hydrogen-poor and argon/carbon-rich conditions [3–5]. And, in 1999, this new material was reviewed under the label of “Nanocrystalline-Diamond Films” [6].

As a class, NCD films cover a wide variety of materials ranging from films with properties approaching to single crystal diamond to others which are useful for specialized applications. In fact, there are intrinsic electrochemical properties of diamond that are independent of the grain size (nano or micro), unequivocally distinguishing them from other commonly used sp²-bonded carbon electrodes. These properties are (i) a low and stable background current; (ii) excellent structural and morphological stability at high temperatures and current density; (iii) good responsiveness for several aqueous and nonaqueous redox analytes without any conventional pretreatment; (iv) long-term response stability; (v) optical transparency in the UV/Vis and IR regions of the electromagnetic spectrum, useful properties for spectroelectrochemical measurements [7].

However, when the size of the structure is decreased, the surface/volume ratio increases considerably and the surface phenomena predominate over the chemistry and physics in the bulk. Thus, there are some specific properties for the NCD films that differentiate them from microcrystalline. In Table 1 are shown some of the differences between NCD (undoped and boron-doped) and boron-doped microcrystalline diamond (BDD).

Thus, there are important features of crystalline materials that need to be well understood in order to improve their application efficiency in a wide range of areas such as mechanics, biomedicine, electrochemistry, and electronics, among others.

2. The Preparation Methods of Nanodiamond Films
The main route towards nanocrystalline diamond films is to use standard techniques to grow polycrystalline diamond films on different substrates [16–19], for example, microwave plasma [20–29] or hot filament [30–36]. The growth of nanometric films may be performed by changing some growth parameters, such as, the application of negative bias on the substrate [37–40], the increase of the methane concentrations [41–45] or by the addition of noble gas to the precursor mixture [10, 46, 47].

The gas mixture, with a high percentage of CH₄ in H₂ (5–20%), provides a type of NCD morphology called cauliflower
or ballas type [48, 49]. Presumably the higher percentage of CH₄ in H₂ increases the twinning, and the non-diamond carbon incorporation thereby reducing the grain size [50]. Thus these NCD films can be grown without an appreciable increase of the roughness on growth surface, but at the cost of increasing the nondiamond component of the film (up to 50% nondiamond carbon).

The most used noble gas has been argon with concentrations above 70 vol.% [19, 22, 23, 42–44, 51]. It promotes an increase of CH₃ and C₂ (and/or C₂H) radical amounts close to the substrate surface which determines the growth morphology [6, 31]. Originally, it was suggested that the C₂ radical played an important role in the growth mechanism [6]. However, recent works have shown that the concentration of CH₃ and C₂H are much greater than C₂, and these species may be more important growth precursors than C₂ under typical nanocrystalline deposition conditions [30, 31, 52].

In general, the other advantage of nanocrystalline diamond films is the possibility of deposition on different kind of substrates. However, two important regards must be considered when selecting a substrate: (i) tolerance of the substrate material to the high deposition temperature (1000–1200 K), and (ii) similarity in the thermal expansion coefficient with that of diamond (1.1 × 10⁻⁶ K⁻¹).

In relation to doped NCD films, they may be grown by adding nitrogen or boron in growth mixture mentioned above to obtain n-type or p-type semiconductor materials, respectively [1]. Boron is the most successful and widely used acceptor in diamond, and the doping can be achieved by adding substances as diborane, trimethyl borane, and boron trioxide. This is because of boron has a low charge carrier activation energy of 0.37 eV [53]. At low doping levels, the diamond acts as an extrinsic semiconductor. At high doping levels the material acts as a semimetal. The success of such a doping will be largely dependent on the dopant position within the films and the nature of the bonding of the dopant atoms to the surrounding of the carbon atoms. The possibility of n- and p-type diamond doping [54, 55] opens the door for a generation of bipolar devices, such as a diamond p–n junction reported by Koizumi et al. [56]. Other dopants have also been tried, such as sulfur and arsenic [57]; however, no systematic results have been obtained so far.

Therefore, this paper will present a short, up-to-date and compact review covering nearly all aspects of nanodiamond electrodes. In next topic will be reported the properties, characterizations, and applications of undoped and boron-doped nanocrystalline diamond electrodes separately.

### 3. Undoped and Boron-Doped Nanocrystalline Diamond Electrodes for Electrochemical Applications

New materials research for electrochemical applications has been a challenge in the last few years. The use of diamond films in electrochemistry is relatively a new field of research. The first article in the field was published in 1983 by Iwaki et al. [58], but the field was really initiated by the important article from Pleskov et al. [59] in 1987.

However, the doping is not a unique way to make dielectric diamond conducting. The NCD structures have the conductance caused by the same structural defects, and also due to continuous network formed by the amorphous carbons that are incorporated in the intercrystallite boundaries during the film growth process [6]. Gruen [6] has observed that when the crystalline size is reduced to nanometer scale, the percentage of carbon atoms located at grain boundary increases drastically with the decrease of grain size. Clearly, the magnitude of the effects on properties is directly proportional to the fraction of carbon atoms residing at the grain boundary. He has concluded that the conduction occurs via π states in the grain boundary and anything chemically or electrochemically that alters the grain boundary bonding influences the electrical conductivity, and as a consequence, the electrical properties of NCD.

Finally, we will report the characteristics, properties and applications of two types of nanocrystalline diamond electrodes, undoped and boron-doped.

#### 3.1. Undoped Nanocrystalline Diamond Electrodes

As mentioned previously, the undoped NCD films are usually deposited from CH₄/H₂ or CH₄/H₂/Ar gas mixture. Nowadays, high quality nanocrystalline and polycrystalline electrodes can be obtained from different commercial sources. Particularly, the film shown in Figure 1 was obtained in Diamond Laboratory of LAS/INPE (São Paulo, Brazil). It was prepared by hot filament chemical vapor deposition (HFCVD) technique on a silicon substrate using a gas mixture of CH₄/H₂/Ar with a flow of 0.5/9.5/90 sccm [44].

The value of argon concentration is very close to values studied by other authors that obtained the smallest grains and better films with argon concentrations at or above 90 vol.% using HFCVD [60, 61] or microwaves system [28, 62]. This film presented a uniform morphology with grains around 50 nm. The micrograph obtained by Field Emission Gun Scanning Electron Microscopy (FEG-SEM) was performed using Zeiss-SUPRA 35 equipment.

<table>
<thead>
<tr>
<th>PROPERTY</th>
<th>NCD</th>
<th>BDD</th>
<th>References</th>
</tr>
</thead>
<tbody>
<tr>
<td>Working potential window</td>
<td>2.5 to 3.0 V</td>
<td>3.0 to 3.5 V</td>
<td>[7–11]</td>
</tr>
<tr>
<td>Conductivity</td>
<td>undoped or doped</td>
<td>only doped</td>
<td>[1, 6, 8, 9]</td>
</tr>
<tr>
<td>Roughness</td>
<td>low</td>
<td>high</td>
<td>[1, 10, 11]</td>
</tr>
<tr>
<td>ΔE_π (mV) – Fe(CN)_₆⁻³/₄</td>
<td>60–170</td>
<td>60 to 80</td>
<td>[7, 11–14]</td>
</tr>
<tr>
<td>Effective surface area</td>
<td>high</td>
<td>low</td>
<td>[15]</td>
</tr>
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Table 1: A comparison of the some properties of the NCD and BDD.
The nanodiamond crystallinity was investigated by X-ray diffraction (XRD) using a high resolution Philips diffractometer, X’Pert model, with the CuKα1 radiation (λ = 1.54 Å) in grazing incident mode with an incident angle of 5°. XRD pattern of film is shown in Figure 2. The XRD spectrum of the NCD film is dominated by the peaks at 43.9°, 54.57°, 75.3°, and 91.5° corresponding to the ⟨111⟩, ⟨210⟩, ⟨220⟩, and ⟨311⟩ diamond diffraction peaks that evidence the presence of crystalline diamond [63]. It should be noted that no peaks associated with graphite or features related to amorphous carbon could be identified in this film.

Raman spectroscopy has become one of the most used tools for the characterization of disordered polycrystalline graphitic carbons. This technique is simple, not destructive and it is possible to determine the quality of diamond film by the ratio of sp³/sp²-carbon bonds [64]. This film was analyzed by micro-Raman scattering spectroscopy (Renishaw microscope system 2000) using the 514.5 nm line of an argon ion laser taking the spectra covering the range from 1000 to 1800 cm⁻¹ as shown in Figure 3.

The film spectrum is characteristic of NCD, showing a broad peak at 1345 cm⁻¹ (D band) that represents a zone-edge A1g mode due to the disorder and a G peak centered at about 1550 cm⁻¹ that corresponds to graphite [65]. The diamond peak at about 1332 cm⁻¹, not observed in visible Raman spectra of NCD films, is generally obscured by the overlapping of D peak, which is more sensitive to non-diamond phases. According to Ferrari and Robertson [66], the D peak is due to the breathing modes of A1g symmetry involving phonons near the K zone boundary while the G peak is due to the bond stretching of all pairs of sp² atoms in both rings and chains [67]. This mode is forbidden in perfect graphite and only becomes active in the presence of disorder. The Raman spectrum also exhibited two bands at 1150 and 1490 cm⁻¹. This pair of peaks has already been discussed as the transpolyacetylene (TPA) segments at the grain boundaries of NCD surface [66].

Taking into account that the nanocrystalline grains are mainly surrounded by graphitic and oxygenated carbon forms, XPS spectrum should reveal a surface enrichment of graphitic, oxygen bonded, and dangling carbon components with respect to the diamond one. This suggestion is adequately confirmed by the analysis of C1s XPS spectrum of this film. A better fitting of the experimental data was obtained assuming the concomitant presence of distinct groups of chemical species, emerging at separate Binding Energies (BE) maxima, in accordance with the analyzed spectrum. As a matter of fact, the residual curve suggests that this result was affected by minor errors. Moreover, the relevant physical parameters related to each component, for example, the mixing Gaussian factor, χ² and FWHM, are meaningful, thus allowing a reliable qualitative and quantitative XPS analysis.

The C1s XPS film spectrum is shown in Figure 4. The C1s peak evidenced the presence of several components, including graphitic (or sp²-like carbon), diamond (or sp³-hybridized carbon) species and, to a less variable extent, oxidation products containing oxygen—carbon bonds. Considering the fitting of data in Figure 4, the most intense peak (II), centered at 284.1 eV, may be attributed to the bulk diamond component (sp³ C–C) and the less intense
component (I), shifted by −0.5 eV with respect to diamond peak, may be assigned to graphitic carbon species (sp2 C–C). The peak (III) corresponds to C–H and the two remaining peaks, centered at higher BE values, could be reasonably assigned to alcoholic (peak IV) and carbonyls (peak V) functional groups, respectively [68].

The electrochemical characteristics of this undoped NCD electrode, immersed in aqueous electrolyte solution, are very close to be observed by others authors. Three electrodes, (work electrode, counter electrode and reference electrode) inside of a single-compartment electrochemical cell were used in this study. The electrodes were not submitted to surface pretreatment before electrochemical measurements and their geometric area in contact with the electrolyte was 0.10 cm². The platinum coil and Ag/AgCl electrodes were used as counter and reference electrodes, respectively. Solutions were deoxygenated with N2 for at least 20 min prior to and blanketed with the gas during the measurements. The treatments of systems called quasi-reversible is associated to reactions that show electron’s transfer kinetic limitations and consequently, for these systems, reverse reactions have to be taken into account. Quasi-reversible systems are those that show electron’s transfer kinetic limitations and consequently, for these systems, reverse reactions have to be considered [69]. In this way, NCD electrode was analyzed by the quasi-reversibility criteria: the separations between the anodic and cathodic peaks (ΔEp) are larger than 59/n mV (where n = 1 is the number of electrons involved in the reaction).

Figure 4: C1s XPS spectra of undoped NCD film grown on a silicon substrate.

The electrochemistry capacitor due to their large superficial area [75].

Electrochemistry response for the NCD film showed a low capacitance and stable background currents. This result is attractive features of diamond for potentially improved signal-to-background in electrochemical assays. The curve also revealed a working potential window around 2.6 V versus Ag/AgCl where the oxidation water begins at 1.8 V and the reduction water begins at −0.8 V (baseline < 2 μA cm⁻²). This value was very close to the results observed by Hian et al. [70], ca. 2.5 V versus SCE, and Foord and Hu [71], ca. 2.8 V versus SCE. Well-defined oxidation (ca. 0.38 V) and reduction (ca. 0.18 V) peaks of the same current magnitude are seen for NCD electrode with a peak potential separation, ΔEp, of 200 mV. The electrode reactions kinetics for this couple are strongly influenced by the amount of exposed edge planes on sp²-bonded carbon as well as the surface cleanliness [72]. Granger and Swain [73] have shown that surface carbon-oxygen functionalities on microcrystalline diamond significantly influence ΔEp with increasing oxygen content causing an increase in the peak potential separation. According to them, the oxygen blocks the surface site that is involved in the reaction on the film surface. Apparently, this affirmation can also be applied to this nanodiamond film.

Gruen et al. [12, 74] have demonstrated that smooth and high-quality diamond films can be produced using fullerene (C₆₀) and CH₄ precursors, taking into account the gas mixture. This result was obtained in argon microwave plasmas without the addition of H₂. Diamond films produced in this way are nanocrystalline, smooth (20 ± 50 nm rms surface roughness typically), electrochemically active (i.e., conductive), and highly reactive. The working potential window for the films is ca. 3.0 V versus SCE and is larger than the ca. 2.5 V window observed for freshly polished glassy carbon. The films also exhibited reasonably good voltammetric responses for Fe(CN)₆³⁻/⁴⁻ and Ru(NH₃)₆³⁺/²⁺, with ΔEp values of 167 and 90 mV, respectively. They concluded that the larger ΔEp at the nanocrystalline film may be related to the presence of surface oxides. These results confirm that the surface cleanliness is important, as well as the electrolyte type and concentration [12].

In general, the porous materials are of scientific and technological interest because of their ability to interact with atoms, ions, and molecules not only at their surfaces, but throughout the bulk of the material. Not surprisingly, traditional applications of porous materials involve ion exchange, adsorption (for separation) and catalysis, and several of these benefits from the high order that can be achieved in solids such as zeolites. In the same way, the growth of microcrystalline diamond on porous silicon (PS) substrate has been studied with the objective of increasing the number of diamond nucleation sites, being a promising material for obtaining better crystalline structure and an excellent electrochemistry capacitor due to their large superficial area [75].

In this context, Ferreira et al. [36] have grown NCD films on a micrometric PS substrate to use as capacitor. The PS substrate was produced by anodic etching using n-type silicon wafers. From the micrographs in Figures 6(a) and 6(b), they observed nanograins with average size from 30 to 50 nm and uniform surface texture covered all the supports among the pores resulting in an apparent microhoneycomb structure.

NCD/PS presented a work potential window at 3.0 V versus Ag/AgCl and a large capacitive background current,
Potential (V versus Ag/AgCl)

Current density (mA/cm²)

(a)

Potential (V versus Ag/AgCl)

Current density (mA)

(b)

Figure 5: CV i-E curves for undoped NCD electrode in (a) 0.5 mol L⁻¹ H₂SO₄ (0.1 V s⁻¹) and (b) 1 mmol L⁻¹ ferrocyanide/0.1 mol L⁻¹ KCl (10 mV s⁻¹), respectively.

Figure 6: SEM images of undoped NCD grown on n-type PS sample. The magnification was increased from (a) to (b) for better visualization of nanograin.

mainly due to increase of electrode surface area as expected for such porous electrode. Taking into account the capacitor applications, they discussed that the double layer capacitive current for NCD/PS was 30 times larger than the as-deposited microcrystalline BDD electrodes. They evaluated the capacitance in the potential range of −0.5 up to 1.0 V versus Ag/AgCl and showed that for BDD electrode; the values in this range were 20 and 40 μF cm⁻². However, NCD/PS electrodes presented superior capacitance in the same range from 230 to 990 μF cm⁻² corresponding to an increase of around 25 times at 1.0 V versus Ag/AgCl. From all these results, they considered the possibility of NCD on PS substrates for electrochemical capacitor applications.

The use of silicon as a substrate for the diamond films growth is the most perfect due to their thermal expansion coefficients are very close. But for several practical applications the brittleness of silicon is forbidden, and then the metal substrates are used as an alternative. Beyond the mechanical resistance, another advantage is the possibility to produce large area electrodes up to the square meter range. The titanium is widely used in many technological applications, such as aeronautics, bioimplants, dental prostheses, and commercial electrodes. Therefore, the combination of diamond films with titanium substrates may expand the range of possible applications [25, 40, 45, 76]. Hian et al. [70, 77, 78] have deposited an adherent nanodiamond film on titanium rods substrates for electroanalysis application. After the film deposition, they compared the metal deposition and stripping processes with gold and copper at nanodiamond and BDD electrodes and concluded that the processes were faster and more efficient at nanodiamond electrodes. They mentioned that the nanodiamond films exhibit significant electrical conductivity due to the graphitic content and high concentration of grain boundaries in the material and offer advantages over BDD in terms of enhanced reactivity [70]. They also observed that the nucleation of gold appeared to be
facile at edge sites, which are abundant on the nanodiamond surface. For the deposition and stripping of both gold and copper, a stripping efficiency (the ratio of electrode dissolution charge to electrodeposition charge) of close to unity was detected even at low concentrations of analyte.

Braga et al. [79] have also shown to be possible to produce hybrid three-dimensional electrodes with NCD films on porous titanium (Ti) substrates. They used the power metallurgy technique to obtain the Ti substrates provided by interconnected and open porous among its volume. Electrochemical response revealed a working potential window around 3.3 V versus Ag/AgCl and a $\Delta E_p = 120$ mV. In the case of the NCD/Ti electrode, the high value of $\Delta E_p$ may be attributed to the presence of a high amount of the sp$^2$-bonded carbon and film roughness. They concluded that such electrode may be applied to different electrochemical applications due to the structural advantages of the metallic Ti structure, the porosity introduced in the bulk material, and chemical properties of the diamond.

Mani et al. [80] have obtained a new nanocomposite containing nanocrystalline diamond and an amorphous sp$^3$ carbon phase that was synthesized by immersing a platinum wire substrate into the plasma. This material exhibited excellent electrochemical properties with wide potential window ($>2.0$ V in $H_2SO_4$) and high degree or reversibility for the dopamine redox couple ($<100$ mV peak separation). In addition, the nanocomposite was mechanically rugged and chemically stable in a variety of acidic and basic environments and did not require any surface preparation or any additional ohmic contacts. They suggested that these nanocomposites could directly be used in several analytical, biomedical, waste remediation, and electroosynthesis applications.

3.1.1. Applications of Undoped Nanocrystalline Diamond Electrodes. The undoped nanodiamond electrodes can be used in different applications due to their electrochemical properties. Besides, in some cases, these electrodes can be modified in multiple paths to change their properties. However, most of them have been used as a biosensor.

The interaction between electrode surface and the analyte that will be analyzed is very important. According to Lawrence and Don [81], the surface of as-grown CVD diamond films is typically terminated with hydrogen atoms. The unpolar hydrogen-terminated surface gives the electrodes a hydrophobic nature, while oxygen-terminated surface gives a hydrophilic nature. Klauser et al. [82] have shown the importance of this interaction when investigated the effect of fetal bovine serum (FBS) on cell adhesion on surfaces of identical roughness and topography but varying the surface chemistries of NCD terminations (hydrogen, fluorine and oxygen terminations). Two different cell lines, porcine renal epithelial cells (LLC-PK1) and carcinoma cells (PANC-1) were cultured on the NCD surfaces with and without 10% FBS in the growth medium. They concluded that the addition of FBS to the growth medium allowed cell adhesion on both hydrophilic and hydrophobic NCD surfaces. In contrast, in FBS-free medium, cell attachment could only be assessed on hydrophilic surfaces. Understanding basic cell-surface interactions on hydrophilic surfaces is complex, and mechanisms of direct cell attachment on hydrophilic surfaces are not as well investigated as protein-mediated cell-surface interactions. Furthermore, protein adsorption is dependent on surface wettability and therefore more degrees of freedom have to be considered. Anyway, NCD offers the possibility to generate cell growth substrates with well-defined surface properties.

Huang et al. [83] have also studied the influence of surface treatments in the immobilization of antibodies on nanodiamond for biosensor applications. They analyzed the anti-Salmonella and the anti-Staphylococcus aureus antibodies. The efficacy of antibody immobilization was evaluated by enzyme-linked immunosorbent assay (ELISA) and the bacterial binding efficiency was analyzed by SEM pictures. They concluded that the immobilization efficacy of both antibodies and bacterial binding efficiency on air plasma treated nanodiamond are better than those of the hydrogen plasma treated. The explanation for this is that the nanodiamond electrodes treated by air plasma had oxidized surfaces, consequently, is more hydrophilic. Thus, the contact between the hydrophilic antibody solution and the hydrophilic nanodiamond surfaces was enhanced.

Indeed, recent works have shown different applications to oxygen-terminated nanodiamond surfaces, including as transducer material for the detection of pH and penicillin concentration [84, 85]. Poghossian et al. [84] have developed a field-effect capacitive EDIS (electrolyte-diamond-insulator-semiconductor) structure as a platform for (bio) chemical sensing. According to them, in contrast to transistor structures, EDIS sensors are simple in layout and cost-effective in fabrication. Usually, no photolithographic process steps or complicated encapsulation procedures are required in case of the capacitive field-effect EDIS structure. Consequently, they characterized the NCD-based field-effect sensors by means of constant-capacitance method. The average pH sensitivity of the O-terminated NCD film was 40 mV/pH. A low detection limit of 5 μM and a high penicillin G sensitivity of 65–70 mV/decade was obtained for an EDIS penicillin biosensor with the adoptively immobilized enzyme penicillinase. Finally, they proposed a model of the drift mechanism in EDIS sensors, as well as an immobilization of biomolecules (DNA and proteins) on NCD films for extending the biosensor capabilities of the EDIS platform.

Another possibility is to obtain modified nanodiamond electrodes, which can be performed by the deposition of layers of different chemistry or biological compounds, for biosensor device as studied by Rubio-Retama et al. [86] and Yang et al. [87]. Rubio-Retama et al. [86] have investigated the functionalization of NCD thin films with horseradish peroxidase (HRP). The electrochemical behavior of the modified NCD surface was characterized by impedance spectroscopy and CV. The proximity of HRP heme groups to the NCD surface allowed direct electron transfer between them. The heterogeneous electron-transfer constant for both processes was calculated to be 0.066 s$^{-1}$, the charge-transfer coefficient $\alpha = 0.49$, and the immobilized enzymatic layer about $2 \times 10^{-10}$ mol cm$^{-2}$. The modified NCD electrode was used as a third generation biosensor for hydrogen peroxide.
determination showing a linear response in the 0.1–45 mmol H₂O₂ range, at +0.05 V versus Ag/AgCl. Thus, they concluded that the immobilized enzyme maintains its activity and good stability. These results confirmed that modified NCD electrodes could be used for in vivo applications or for optimizing clinical methodologies that are based on the measurement of hydrogen peroxide produced during the analytical process.

Meanwhile, Yang et al. [87] have shown that NCD thin films covalently modified with DNA oligonucleotides provide an extremely stable, highly selective platform in subsequent surface hybridization processes. They used a photochemical modification scheme to modify chemically the NCD surface, producing a homogeneous layer of amine groups that serve as sites for DNA attachment. After linking DNA to the amine groups, hybridization reactions with fluorescently tagged complementary and noncomplementary oligonucleotides showed no detectable non-specific adsorption, with extremely good selectivity between matched and mismatched sequences. Comparison of DNA-modified NCD film with other commonly used surfaces for biological modification, such as gold, silicon, glass, and glassy carbon, showed that diamond was unique in achieve a high stability and high sensitivity and while it also was compatible with microelectronics processing technologies.

In general, the use of carbon materials has promoted great interest for fuel cells and supercapacitor electrodes [88]. Also called electrochemical capacitor, they have been extensively studied due to the increasing demand for a new kind of electrical energy accumulators of long durability (over 10⁶ cycles) and high specific power (more than 10 kW/kg) [89]. Then, the study of new hybrid nanomaterials is very important for understanding and promoting new technologies in this area. Almeida et al. [90] have shown that the NCD formation on carbon fiber (CF) structures produces an innovative material, the diamond porous electrode, with a large surface area and high capacitive response. Furthermore, NCD grown directly on CF substrate promotes an electrode with low electric resistance, improving the device performance. In Figure 7 is showed the CV of NCD/CF electrode in 0.5 mol L⁻¹ H₂SO₄ solution at the scan rates of 100 and 10 mV s⁻¹.

This result showed that the NCD/CF electrode has the characteristic behavior of an ideal capacitor with rectangular current-potential responses curves. As discussed by Chen et al. [91], using carbon nanotubes, the achievement of rectangular-shaped CV over a wide range of scan rate is the ultimate goal for electrochemical double-layer capacitors. This behavior is very important for practical applications when two contributions are assigned: a higher energy density due to the wide potential range and a higher power density associated to the scan rate increase. This behavior was confirmed by the inset in Figure 7. The currents at 0.6 V were plotted as a function of scan rate, assuming that there is a contribution of non-Faradaic reactions at this potential. The plot of the NCF/CF electrode depicts a linear dependence with scan rate for the whole range studied up to 100 mV s⁻¹. This result should also be pointed out since for an ideal capacitor, its capacitance is independent of the frequency, so the charge stored by a capacitor is proportional to the imposed potential. Apparently, the pair of broad redox peaks (A and A’) that appear in Figure 7 may be the oxidation/reduction of surface functional groups on CF substrate.

They also measured the specific capacity from the linear regression of the graph of current density in function of the scan rate (inset in Figure 7). The value for NCD/CF was 2.6 mF cm⁻². Finally, they compared this value with other values reported in the literature. The best comparison with data already presented in the literature was the nanohoneycomb structures of the BDD films that were investigated by Yoshimura et al. [92]. Particularly, the specific capacity for a nanohoneycomb electrode (60 × 500 nm) in an aqueous solution was 1.83 mF cm⁻², which is lower but in the same order of magnitude for this NCF/CF electrode studied.

3.2. Boron-Doped Nanocrystalline Diamond Electrodes. A second type of nanodiamond electrodes which seems to become more important is a boron-doped nanocrystalline diamond (BDND). These films can be obtained using the same conditions of undoped-NCD film growth as mentioned previously. The doping can be reached by adding substances containing boron in the gas mixture. Rarely, the morphology is different from that shown for undoped-NCD. However it may vary slightly according to the experimental conditions, substrate used, and so forth [93–95]. In Figure 8 is shown the surface of BDND film grown on a silicon substrate obtained in Diamond Laboratory of LAS/INPE (São Paulo, Brazil). Scanning Electron Microscopy (SEM) image of BDND was performed using a JEOI JSM-5310 microscope system. It showed that the morphology is quite similar to that of unfaceted CVD ballas diamond, with grains tended to form agglomerates. These agglomerates have approximately 1.5 μm of diameter with grains smaller than 30 nm. NCD films with agglomerates grown on a silicon substrate were also reported by Yang et al. [28]. They observed the cauliflower or ball-shaped diamond formation, so-called

![Figure 7: CV i-E curves for NCD/CF electrode in 0.5 mol L⁻¹ H₂SO₄ aqueous solution. Scan rate: 100 mV s⁻¹ (solid line) and 10 mV s⁻¹ (dash line).](image-url)
CVD ballas diamond, when argon concentrations above 30% were used. They discussed that ballas diamond is nearly pure diamond with strongly twinned microstructure and grows at the transition from faceted diamond to graphite depositions. This film was prepared by HFCVD technique using the following growth parameters: temperature of the 900 K, pressure of the 6.7 KPa, deposition time of the 6 h, and gas mixture of CH4/H2/Ar with a flow of 1/19/80 sccm.

Boron doping was obtained by forcing H2 through a bubbler with B2O3 dissolved in methanol. The doping level corresponds to the acceptor concentrations at about 1020 cm−3 atoms B/C, calculated from Mott-Schottky plot analysis. The presence of boron incorporation in the film can be observed from Raman spectrum shown in Figure 9. The spectrum covered a range from 300 to 3500 cm−1.

Eight features were identified in the Raman spectrum of BDND film. The diamond peak is visible, and shifted to lower wavenumber (1300 cm−1) that is related to impurities formed in heavily doped films showing a metallic conductivity [96]. The bands at 1350 and 1550 cm−1 correspond to the D and G band, respectively. Besides, the spectrum exhibited a shoulder at 1150 cm−1 and a peak at 1490 cm−1 related to TPA at the grain boundaries of NCD surface. The broad bands at about 500 and 1220 cm−1 present in these films are still subject to an intense debate. They have been associated with the actual boron incorporation in the lattice, rather than the hole concentration [97]. The presence of the 500 cm−1 peak is attributed to the concentration increase of the boron pairs. These boron pairs have local vibration modes giving wide bands at about of 500 cm−1 [97]. In addition, the band centered at 1220 cm−1 is attributed to the Fano interference between the discrete phonon state and the electronic continuum. Pruvost and Deneuville [98] have suggested that the Fano effect appears above a critical percolation threshold for the achievement of the metallic conductivity on the boron impurity band. Meanwhile, Ager et al. [99] have reported that the Fano effect is attributed to the transition from the broadened impurity band to continuum states composed of the excited acceptor and valence band states.

In the following, the graph of Figure 10 represents the Mott-Schottky plot of as-grown BDND electrode. The physical meaning of a Mott-Schottky plot is related to the effect of potential E on the thickness of the space-charge layer in the semiconductor. The intercept of the linear part of the curve with the potential axis at C−2 = 0 represents the flat-band potential (E_{FB}), while the slope of the curve allows to determine the acceptor densities in the semiconductor [100]. The value of E_{FB} was about +2.4 V versus Ag/AgCl.

Several works describe the use of electrochemical impedance spectroscopy as well as the capacitance-potential measurements to demonstrate the differences in electrode behavior after cathodic or anodic pretreatment of the BDD films [101–103]. For example, Actis et al. [101] have mentioned that the values of the flat band potentials for H-terminated BDD and for photochemically oxidized BDD were 0.52 V and 1.11 V versus SCE, respectively. Becker and Jüttner [104] have explained the occurrence of the
resistance associated to the high-frequency element in the BDD impedance by a partial blocking of the diamond electrode surface. However, this resistance is reduced when the BDD surface undergoes the cathodic treatment. This could be related to a superficial conductive layer (SCL) that exists on hydrogen-terminated diamond surface and it can improve the charge transfer and may explain the enhanced electrochemical response [103]. Furthermore, according to Girard et al. [105], a notable positive shift for $E_{FB}$ in the BDD as-grown electrode from 1.0 to 3.0 V versus Hg/Hg$_2$SO$_4$ was observed after the anodic process that contributed to the increase of oxygen terminations. This is also supported by Simon et al. [106] that have reported a positive shift in $E_{FB}$ as characteristic for the formation of C–O structures. Considering the fact that the source of boron doping is a solution of methanol and B$_2$O$_3$, it is expected that there was the presence of oxygen-terminated on the surface of this film.

In relation to the electrochemical characteristics of this BDND electrode, its properties are very close to be observed by other authors. CV $i$-$E$ curve for this film in 0.5 mol L$^{-1}$ H$_2$SO$_4$ (0.1 V·s$^{-1}$) and the curve obtained in 1 mM of Fe(CN)$_6^{3−/4−}$ + 0.5 mol L$^{-1}$ H$_2$SO$_4$ (0.1 V·s$^{-1}$) as shown in Figure 11.

Electrochemistry response for the BDND film showed a low capacitance and stable background current, around 3 μA cm$^{-2}$ at 500 mV. The working potential window for this film is approximately 2.3 V versus Ag/AgCl where the oxidation water begins at 1.8 V and the reduction water begins at −0.5 V. This value is approximately the same as observed by Siew et al. [15], ca. 2.6 V versus Ag/AgCl, and Zhao et al. [107], ca. 2.8 V versus SCE, but, slightly lower than the values obtained by Hupert et al. [7], Wang et al. [11], and Show et al. [72], ca. 3.0 V versus Ag/AgCl. Regardless of differences between the values of working potential window, the value of the peak potential separation ($\Delta E_p$) observed for all the films [7, 13, 107] was very similar to ours results, approximately 80 mV. Remembering that a lower $\Delta E_p$ (∼59 mV) reflects the rapid reaction kinetics at the electrode surface and is compatible with the activity of the same.

3.2.1. Applications of Boron-Doped Nanocrystalline Diamond Electrodes. Boron-doped nanocrystalline diamond electrodes can be used for a multitude of applications because of their unique electrochemical properties that largely differ from that of conventional electrode materials. The electrochemical process of these electrodes permit to obtain results that was not possible with conventional electrodes. Some of the results are related to organic substances which have been determined so far with BDND electrodes, such as aminobiphenyls [108], ganciclovir [109], oxalic acid [110], DNA [111], glucose [107, 112, 113], protein [114], and dopamine [15].

The determination of heavy metal ultratrices is a tough challenge for analysts. Human activity, principally during the last two centuries, has released these toxic metals into the environment and now the impact on the health of humans, animals, and plants is obvious. Spectroscopic and electroanalytical techniques have been widely used, but the principal difference between them is related to the instrumental cost. Electroanalytical techniques are simple to use in situ and the apparatus is easy to handle for measurements in rivers or lakes.

In the recent past and nowadays, inductively coupled plasma atomic emission spectroscopy (ICP-AES), inductively coupled plasma mass spectroscopy (ICP-MS), and related techniques have been widely used to determine low levels of heavy metals in pharmaceutical drugs, food and fish, wine, highly concentrated salt water, or marine microalgae Fucus [115]. However, electroanalytical techniques may compete with spectral methods for selected heavy metals such as copper, lead, cadmium, and zinc because these four metals are known as reversible (rapid electron exchange) and their signals are wide even at low concentration [72, 115, 116]. Using anodic stripping voltammetry (ASV), Tall et al. [115] and Show et al. [72] were able to detect and quantify Ag(I), Cu(II), Pb(II), Cd(II), and Zn(II) as shown in Table 2. The difference of values presented in Table 2 is related to the experimental conditions used by each author. The results using BDD obtained by McGaw and Swain. [117] were also included in Table 2 to show the advantages of BDND to detect these metals.

Both authors [72, 115] concluded that for the metals studied, the BDND electrode provides good sensitivity, low limits of detection, valuable response precision, and superb response stability for several contaminated samples, such as lake and well water, tap water, wastewater treatment sludge, and contaminated soil.

Some BDND electrodes have been modified superficially with the purpose to absorb a specific substance on their surfaces. The modifying agents of surface can promote selective recognition due to charge transfer, adsorption and ion exchange, or specific biological interactions. Yang et al. [118] have shown the possibility to use a surface electrochemical reaction to achieve electrically addressable biomolecular functionalization of BDND films. They provided a pathway for arrays fabrication of distinct biomolecular recognition elements on diamond surfaces, without the use of microfluidics or spoting methods. The electrically addressable functionalization started with BDND films, followed by functionalization of the diamond with nitro groups. The key to achieve electrically addressable biomolecular functionalization lies in the ability to reduce nitro groups selectively on specific electrodes to primary amines, followed by reaction with bifunctional linkers that will selectively react with the amines and covalently link them to DNA or other biomolecules of interest.

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<td>Ag(I)</td>
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<tr>
<td>Cu(II)</td>
<td>0.64</td>
<td>3.0</td>
<td>10.0</td>
</tr>
<tr>
<td>Pb(II)</td>
<td>2.07</td>
<td>3.8</td>
<td>5.0</td>
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<td>Cd(II)</td>
<td>1.12</td>
<td>1.2</td>
<td>1.0</td>
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<td>Zn(II)</td>
<td>6.54</td>
<td>5.0</td>
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incorporated sp2 state carbon as charge transfer mediators. Transfer is faster on the BDND than BDD because of the high chemical and electrochemical stability of them. Furthermore, the direct electron transfer between Cyt c− and the BDND surfaces were treated by anodic polarization (2.8 V versus Ag/AgCl) for 10 s followed by cathodic polarization (−2.8 V versus Ag/AgCl) for 10 s. This procedure was necessary to restore the initial electrode activity. The electrode presented a well-defined current profile for each phenolic compound, and the electrode efficiency was maintained even after several measurements. The oxidation peak potential at 1.16 V, 1.22 V, and 1.52 V versus Ag/AgCl, respectively.

Zhou et al. [13] have also got some interesting results from the use of photochemical functionalization on BDND electrodes. They used a photochemical reaction scheme to modify hydrogen-terminated BDND surfaces chemically using a vinyl group of undecylenic acid methyl esters, followed by hydrolyzation of the esters under basic conditions to produce a monolayer of carboxylic groups on the surfaces. Cyt c was covalently immobilized on the resulting carboxyl-terminated BDND electrode through carbodiimide coupling reaction. For comparison, they prepared counterpart biosensors in which Cyt c was immobilized on BDD and glassy carbon (GC) electrodes prepared by the same procedure. The reproducibility and stability of the Cyt c-modified BDND electrode were investigated by the measurement of the response to 100 µM H2O2 in 0.1 M PBS (pH 7.0). The relative standard deviation (RSD) is 2.1% for 10 successive assays. The long-term stability of the developed enzyme electrode was determined every 3 days, and 85% of its initial activity can be obtained after 6 weeks, while the Cyt c-modified BDD and GC electrodes retained 80% and 25% of their initial activity after 6 weeks. This result suggests that the stability of Cyt c-modified BDND electrode is nearly equivalent to that of the Cyt c-modified BDD electrode, but is significantly higher than that of the Cyt c-modified GC electrode. The superior stability of the Cyt c-modified BDND electrode may be the result of the biocompatible microenvironment for the enzyme provided by the doped diamond electrodes and the high chemical and electrochemical stability of them. Furthermore, the direct electron transfer between Cyt c-modified and the electrodes was obtained and the electron transfer is faster on the BDND than BDD because of the incorporated sp2 state carbon as charge transfer mediators on BDND surface. So, they concluded that these results make the BDND thin film an interesting candidate for the study of the direct electrochemistry of redox proteins and their sensing applications.

Currently, the water treatment is the application that most has been investigated with diamond electrode.
For any quantitative method there is a range of analyte concentrations on which the method can be applied. In the low concentration range, the limiting factors are the values of detection and quantification limits [123]. The detection limit of phenol was investigated by square wave voltammetry (SWV) [124]. In this technique, the net current (\(i_{\text{net}}\)) centered on the redox potential, is obtained by taking the difference between the forward and reverse currents (\(i_{\text{f}} - i_{\text{rev}}\)). The current peak height is directly proportional to electroactive species concentration and the direct determination of the detection limit is possible. Figure 13 shows the square wave voltammogram for BDND electrode. The BDND electrode presented a well-defined current profile as a function of the phenol concentration and an excellent accuracy of phenol oxidation peak at 1.12 V versus Ag/AgCl. In Figure 13, the inset corresponds to the analytical curve in the current peak versus the concentration in the range of 30 to 130 \(\mu\)mol L\(^{-1}\) for each electrode. From linear regression analysis of an analytical curve was found this equation:

\[
i_{p} = (-2.5057 \times 10^{-7} \pm 1.1783 \times 10^{-7})
+ (1.3522 \times 10^{-7} \pm 1.1716 \times 10^{-9}) (1)
\times [\text{phenol}].
\]

This equation was used to evaluate the detection limit (DL) and quantification limit (QL). The DL and QL were calculated from the criterion DL = \(3\sigma/\theta\) and QL = \(10\sigma/\theta\), respectively, where \(\sigma\) denotes the standard deviation of arithmetic media of the currents obtained from ten voltammograms of blanks and \(\theta\) is the slope of analytical curves [124]. The BDND electrode presented a phenol DL of 0.1 mg L\(^{-1}\) and phenol QL of 0.4 mg L\(^{-1}\).

In Figure 13 also appears a voltammogram identified as “standard solution”, but it was not considered in the previous analytical curve. This solution of 8 mg L\(^{-1}\) was prepared from a phenol standard solution of SPECSOL (SRM 136f NIST-USA) to validate the results obtained from the BDND electrode using SWV and chromatographic techniques. The chromatography analyses were performed using Ion Chromatograph (850 Professional IC, Metrohm) equipped with an amperometric detector (791 VA) and a phenol column (Protonsil Enviro PHE 3 \(\mu\)m). The eluent used for this analysis was 20 mmol L\(^{-1}\) KNO\(_3\) + 0.5 mmol L\(^{-1}\) H\(_2\)SO\(_4\) + 30% methanol + ultrapure deionized water.

The values presented below were obtained from the average of three measurements. From the equations it was possible to determine the values of phenol standard sample measured using the BDND electrode. The value was 8.2 ± 0.2 mg L\(^{-1}\). The same standard solution sample was also injected in the Ion Chromatograph and the value obtained was 7.9 ± 0.1 mg L\(^{-1}\). As preliminary tests, the results showed that the methodology using the BDND electrode and SWV was very efficient.

Muna et al. [119] have also studied the efficiency of BDND electrode using other analytical techniques. They showed the results of amperometric detection of phenol coupled with Flow Injection Analysis (FIA) and High Performance Liquid Chromatography (HPLC). The values of QL presented were 0.3 mg L\(^{-1}\) and 0.1 mg L\(^{-1}\) using the FIA and HPLC, respectively. In addition, they mentioned that the QL for the phenolic analytes in their HPLC-EC method is comparable to those reported for Environmental Protection Agency (EPA) methods 1625. So, they confirmed a new possibility for use of this electrode.
4. Conclusions and Outlook

The nanotechnology seeks to study the properties of nanoscale objects and their use in developing devices with these dimensions. This study includes a search by a decrease in materials, targeting a space-saving and energy, and an exploration of new effects that occur at the nanometer scale. Its applications represent a new challenge that includes the fields of physics, chemistry, biology, engineering, and pharmacy, and due to its recent development the nanotechnology has enormous potential to impact science and economics.

Conducting nanodiamond with exceptional hardness, inertness, and stability has been proven as a versatile electrode material for a wide variety of applications. There are several commercial sources that market conducting diamond electrodes for a wide variety of applications. There are several commercial sources that market conducting diamond electrode materials for electroanalysis of many chemistry devices enable the study of very fast electrode kinetics and enhance the response of many electroanalytical sensors. Apparently, the undoped nanodiamond occupies a special place as an electrode material in biosensing applications, while the BDND can be considered as one of the most ideal electrode materials for electroanalysis of many chemistry compounds.

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